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# FGA20N120FTD

## 1200 V, 20 A Field Stop Trench IGBT

### Features

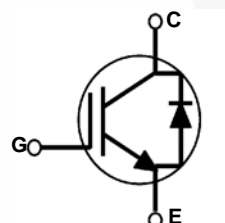
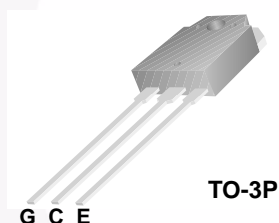
- Field Stop Trench Technology
- High Speed Switching
- Low Saturation Voltage:  $V_{CE(sat)} = 1.6\text{ V @ } I_C = 20\text{ A}$
- High Input Impedance
- RoHS Compliant

### Applications

- Induction Heating, Microwave Oven

### General Description

Using advanced field stop trench technology, Fairchild's 1200V trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche ruggedness. This device is designed for induction heating and microwave oven.



### Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector to Emitter Voltage	1200	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 25$	V
$I_C$	Continuous Collector Current @ $T_C = 25^\circ\text{C}$	40	A
	Continuous Collector Current @ $T_C = 100^\circ\text{C}$	20	A
$I_{CM}$ (1)	Pulsed Collector Current	60	A
$I_F$	Diode Continuous Forward Current @ $T_C = 25^\circ\text{C}$	20	A
	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	10	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	298	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	119	W
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

#### Notes:

1: Repetitive rating, Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.42	$^\circ\text{C/W}$
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	2.0	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA20N120FTDTU	FGA20N120FTD	TO-3P	Tube	N/A	N/A	30

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 1 mA	1200	-	-	V
I <sub>CES</sub>	Collector Cut-Off Current	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V	-	-	1	mA
I <sub>GES</sub>	G-E Leakage Current	V <sub>GE</sub> = V <sub>GES</sub> , V <sub>CE</sub> = 0 V	-	-	±250	nA
On Characteristics						
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 20 mA, V <sub>CE</sub> = V <sub>GE</sub>	3.5	5.9	7.5	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V T <sub>C</sub> = 25°C	-	1.59	2	V
		I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V, T <sub>C</sub> = 125°C	-	1.85	-	V
Dynamic Characteristics						
C <sub>ies</sub>	Input Capacitance	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V, f = 1 MHz	-	3080	-	pF
C <sub>oes</sub>	Output Capacitance		-	95	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance		-	60	-	pF
Switching Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 20 A, R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V, Resistive Load, T <sub>C</sub> = 25°C	-	30	-	ns
t <sub>r</sub>	Rise Time		-	79	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	143	-	ns
t <sub>f</sub>	Fall Time		-	217	320	ns
E <sub>on</sub>	Turn-On Switching Loss		-	0.42	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.71	1.05	mJ
E <sub>ts</sub>	Total Switching Loss		-	1.13	-	mJ
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 20 A, R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V, Resistive Load, T <sub>C</sub> = 125°C	-	29	-	ns
t <sub>r</sub>	Rise Time		-	93	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	147	-	ns
t <sub>f</sub>	Fall Time		-	259	-	ns
E <sub>on</sub>	Turn-On Switching Loss		-	0.47	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.86	-	mJ
E <sub>ts</sub>	Total Switching Loss		-	1.33	-	mJ
Q <sub>g</sub>	Total Gate Charge	V <sub>CE</sub> = 600 V, I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V	-	137	-	nC
Q <sub>ge</sub>	Gate to Emitter Charge		-	23	-	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	65	-	nC

**Electrical Characteristics of the Diode**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max	Unit
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25°C	-	1.3	1.7	V
			T <sub>C</sub> = 125°C	-	1.3	-	
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> =20 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	447	-	ns
			T <sub>C</sub> = 125°C	-	485	-	
I <sub>rr</sub>	Diode Peak Reverse Recovery Current		T <sub>C</sub> = 25°C	-	48	-	A
			T <sub>C</sub> = 125°C	-	50	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge		T <sub>C</sub> = 25°C	-	10.8	-	μC
			T <sub>C</sub> = 125°C	-	12	-	

## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

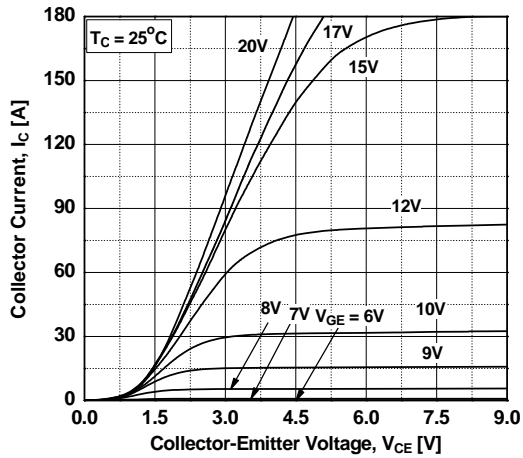


Figure 2. Typical Output Characteristics

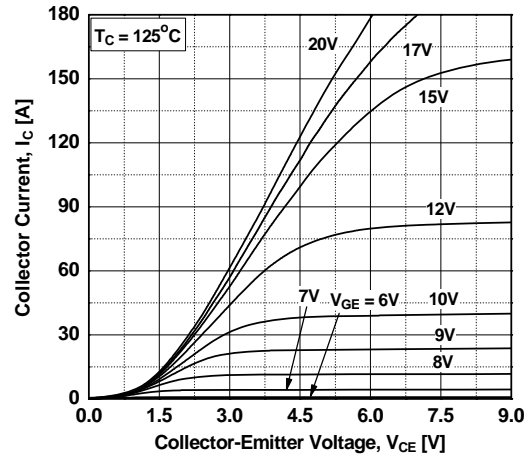


Figure 3. Typical Saturation Voltage Characteristics

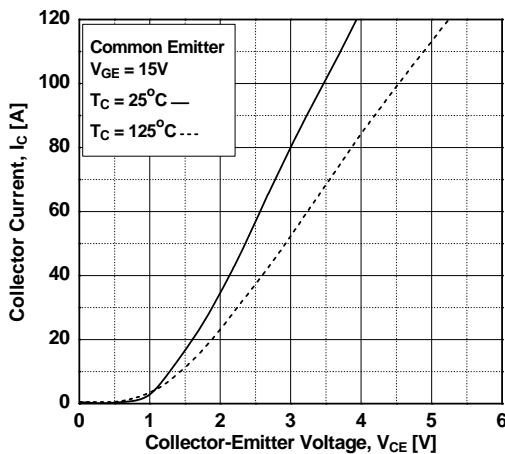


Figure 4. Transfer Characteristics

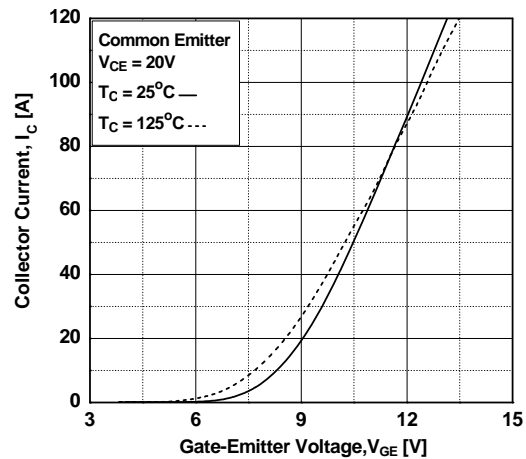


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

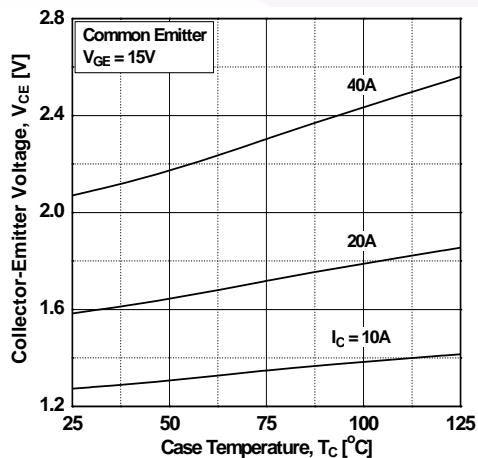
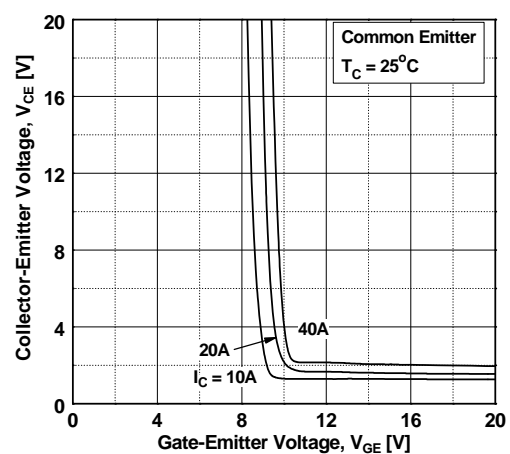


Figure 6. Saturation Voltage vs. Vge



## Typical Performance Characteristics

Figure 7. Saturation Voltage vs.  $V_{GE}$

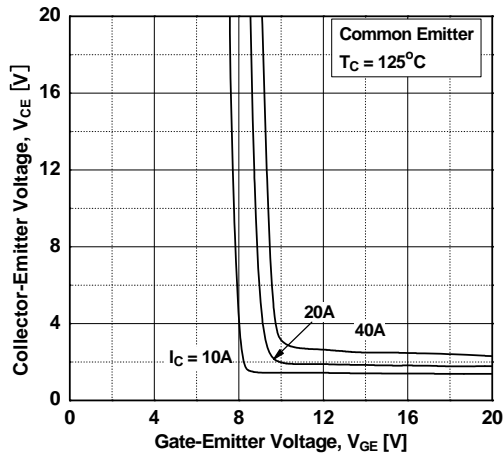


Figure 8. Capacitance Characteristics

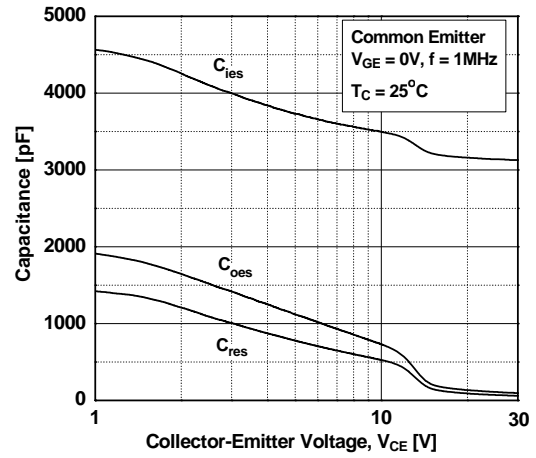


Figure 9. Gate charge Characteristics

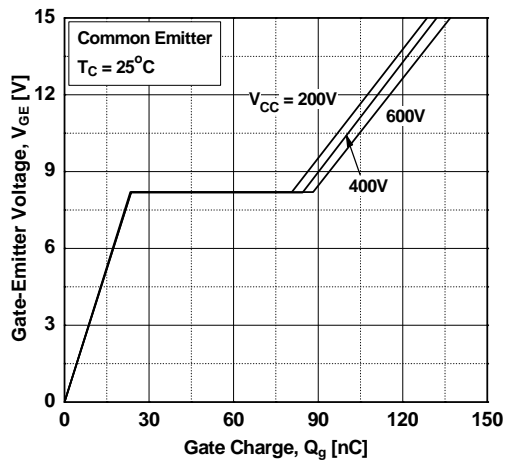


Figure 10. SOA Characteristics

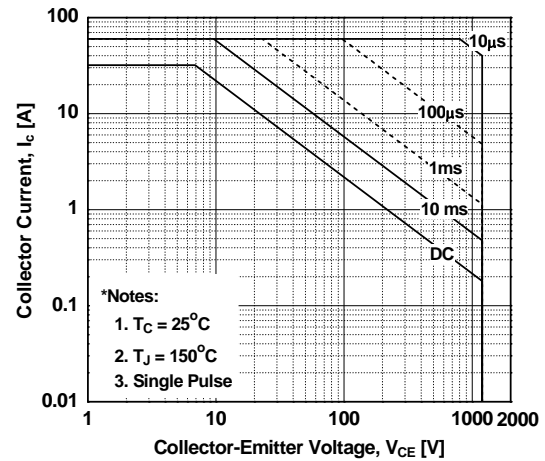


Figure 11. Turn-on Characteristics vs. Gate Resistance

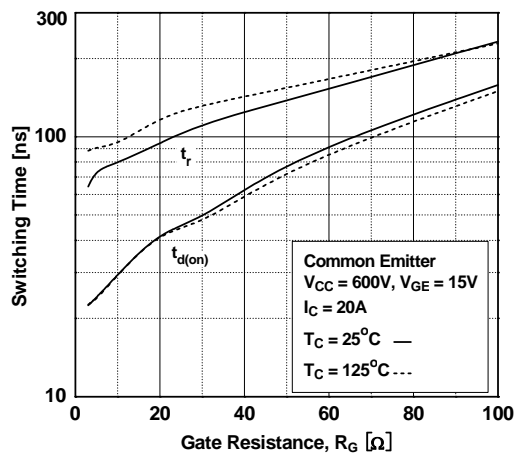
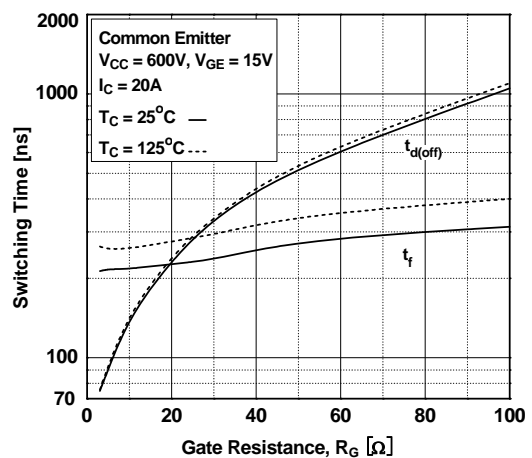


Figure 12. Turn-off Characteristics vs. Gate Resistance



## Typical Performance Characteristics

Figure 13. Turn-on Characteristics vs. Collector Current

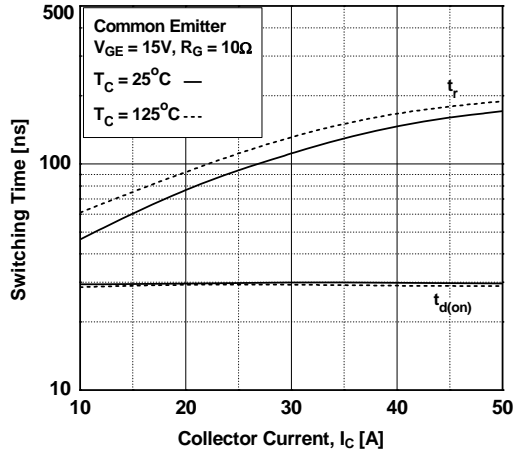


Figure 14. Turn-off Characteristics vs. Collector Current

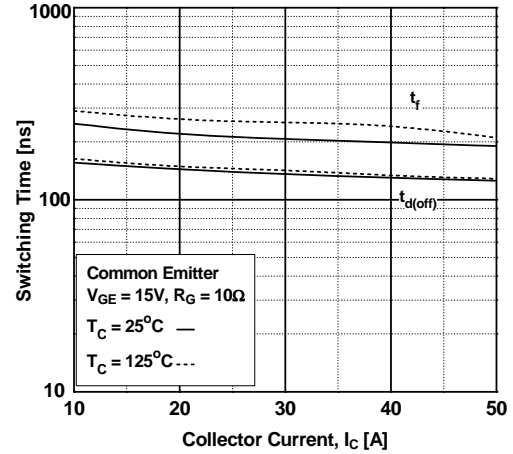


Figure 15. Switching Loss vs. Gate Resistance

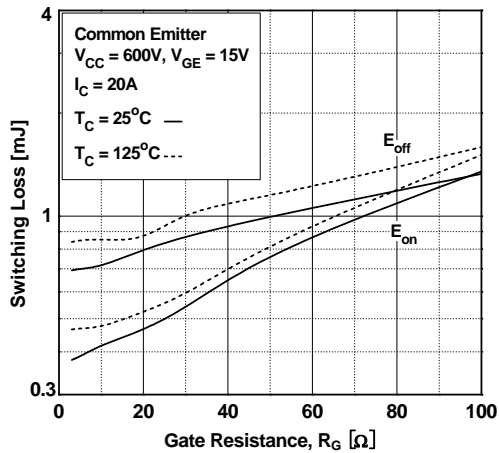


Figure 16. Switching Loss vs. Collector Current

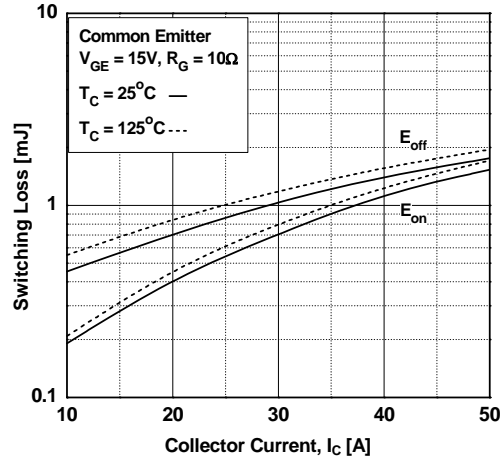


Figure 17. Turn off Switching SOA Characteristics

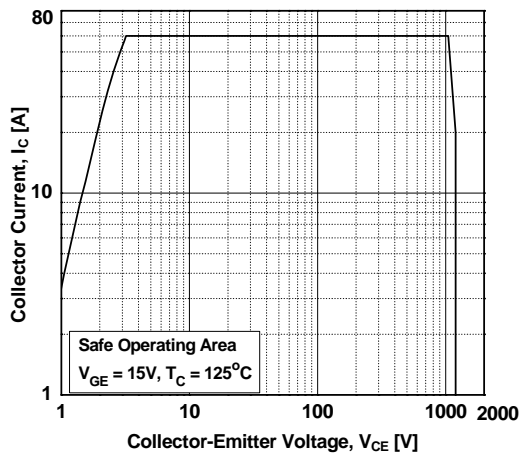
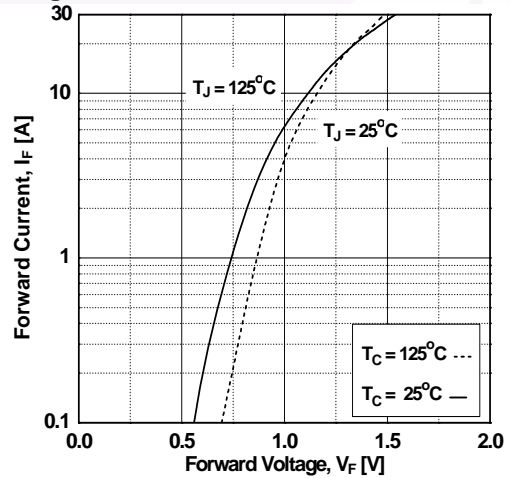


Figure 18. Forward Characteristics



## Typical Performance Characteristics

Figure 19. Reverse Recovery Current

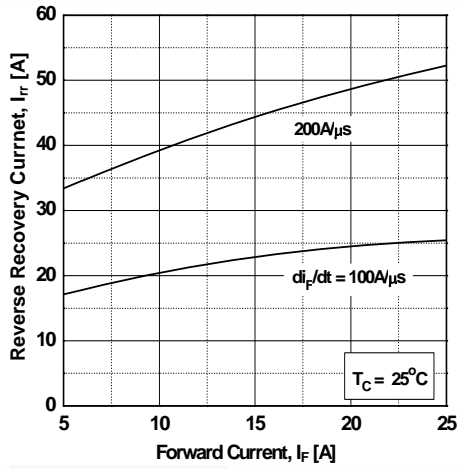


Figure 20. Stored Charge

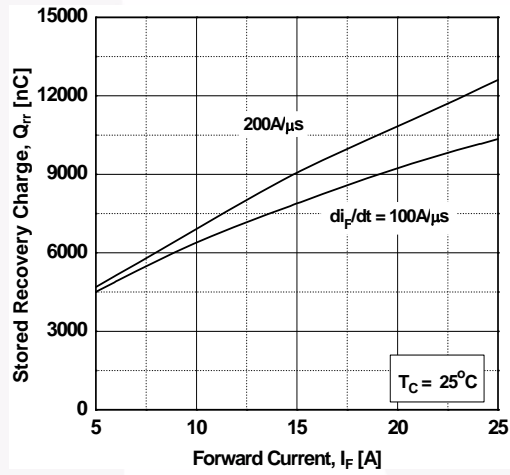


Figure 21. Reverse Recovery Time

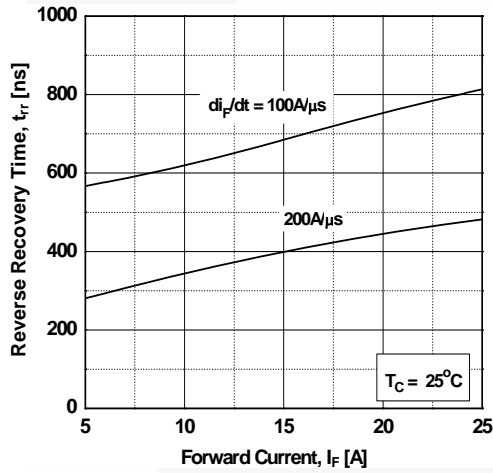
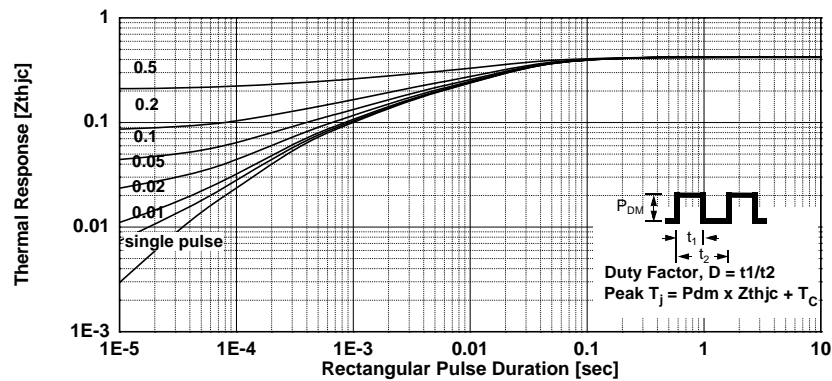


Figure 22. Transient Thermal Impedance of IGBT





## Mechanical Dimensions

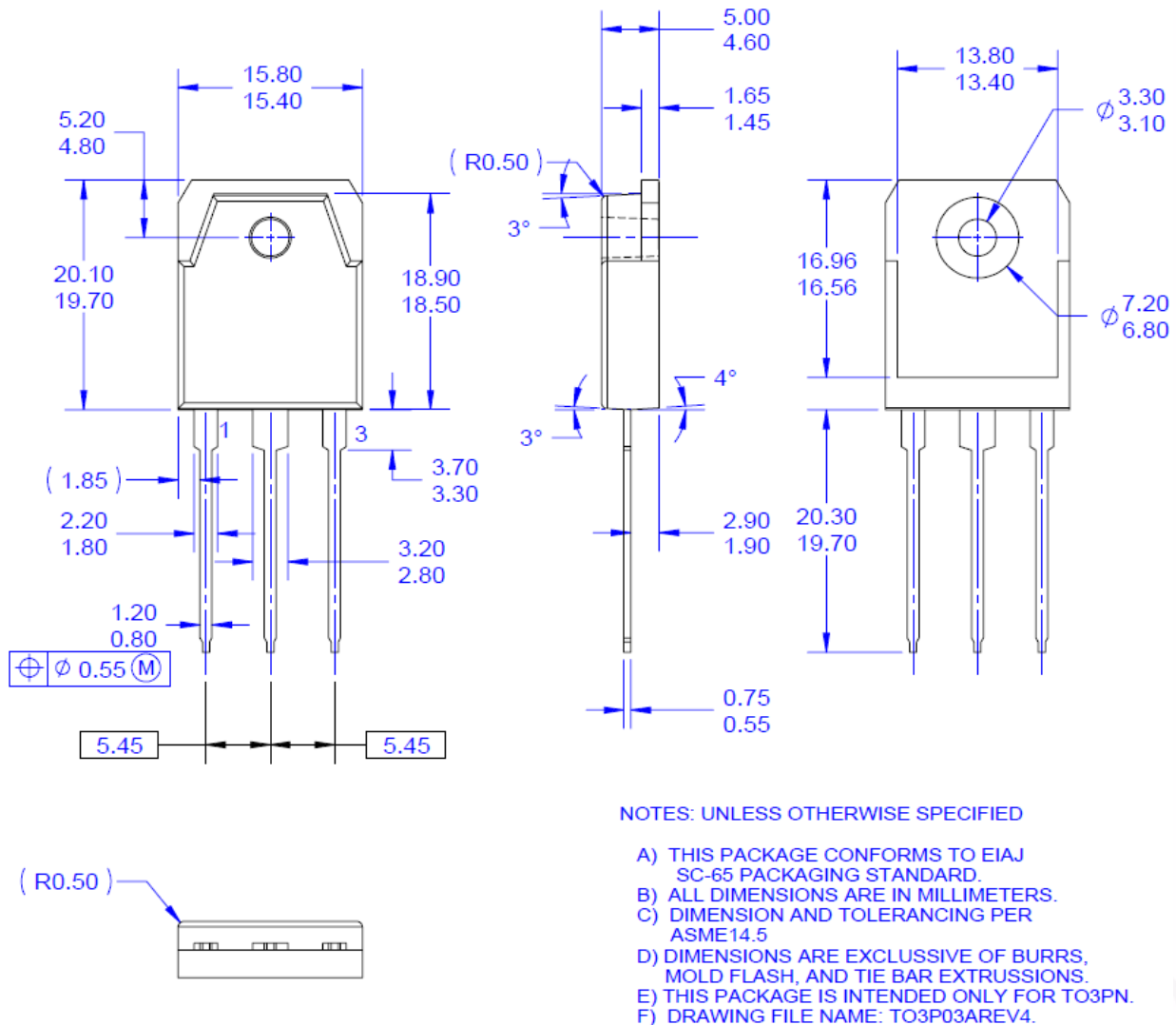


Figure 23. TO-3P 3L - 3LD, T03, PLASTIC, EIAJ SC-65

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